

DIP Workshop – Technion (19/03/2013)

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Topics studied in the framework of the DIP project

1. Superconductivity in HTS nano wires

Student in charge: Daniel Levi

Collaboration: Gad Koren

2. Quantum effects in HTS/LTS nano-loops

Student in charge: Omri Sharon

Collaboration: Elke Scheer
Ivan Bozovic'

Magnetoresistance anomalies in **ultra-thin granular** $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ wires

Why **high- T_c** SC?

Why **granular**?

Why **ultra-thin**?

Why **nano**?

D-wave pairing symmetry

Josephson π -junctions

Confinement

Minimizing the available conduction channels

Summary of results

1. Magnetoresistance oscillations
2. Negative magnetoresistance at low fields
3. Negative magnetoresistance slope in the Tesla regime

ALL PHENOMENA IN THE SAME SAMPLE

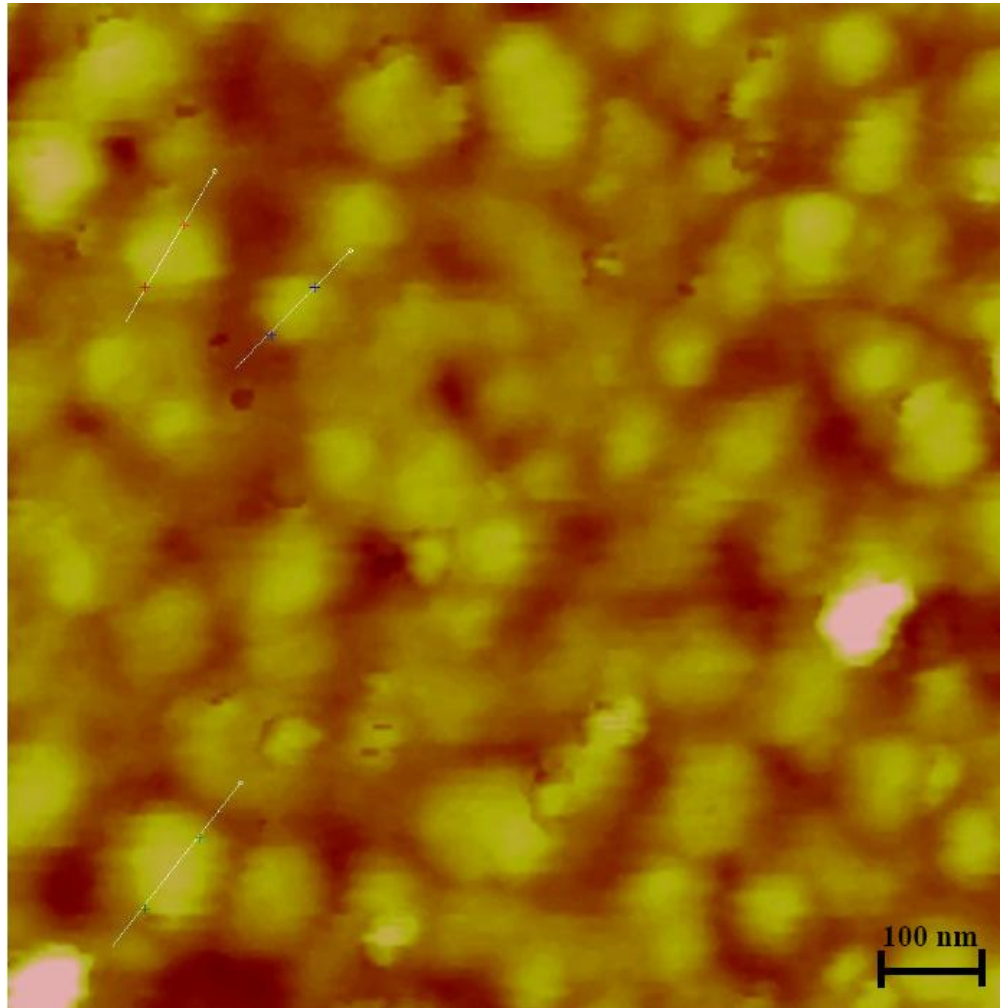
Origin

Granularity

Confinement

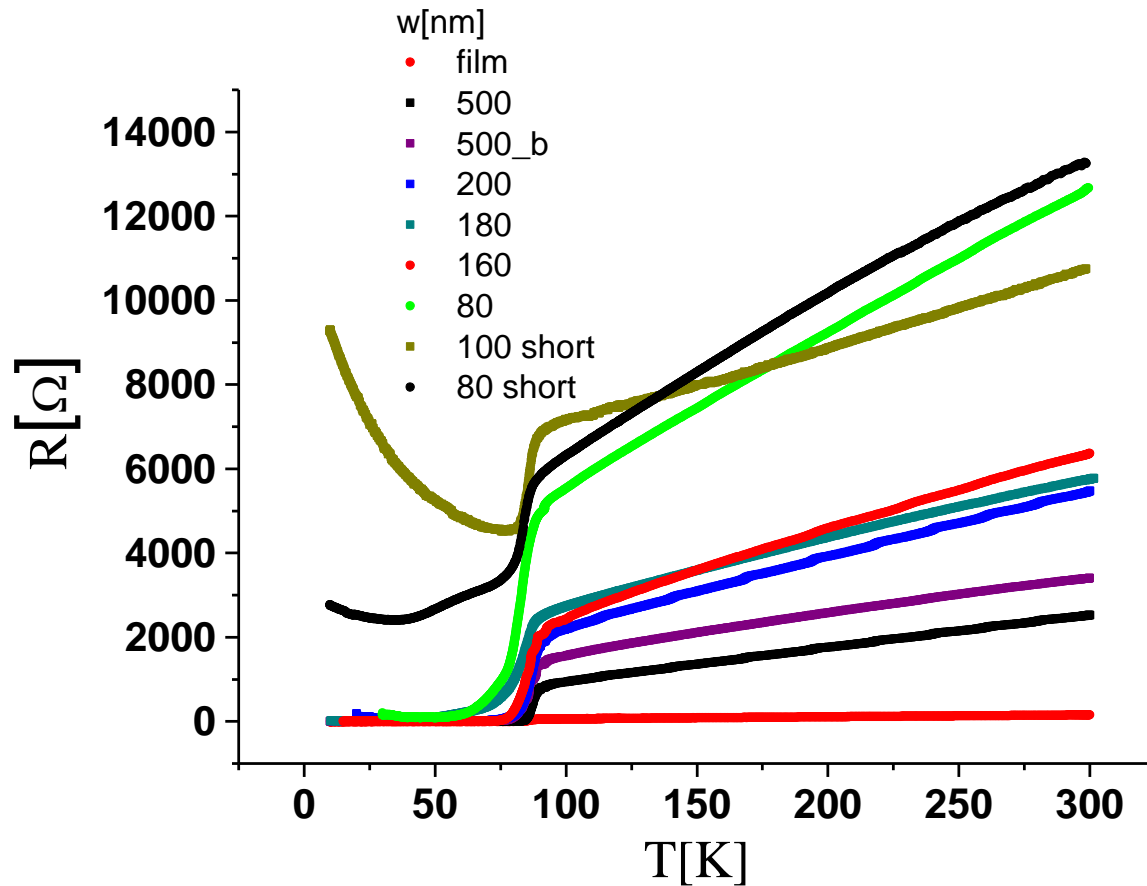
D-wave symmetry

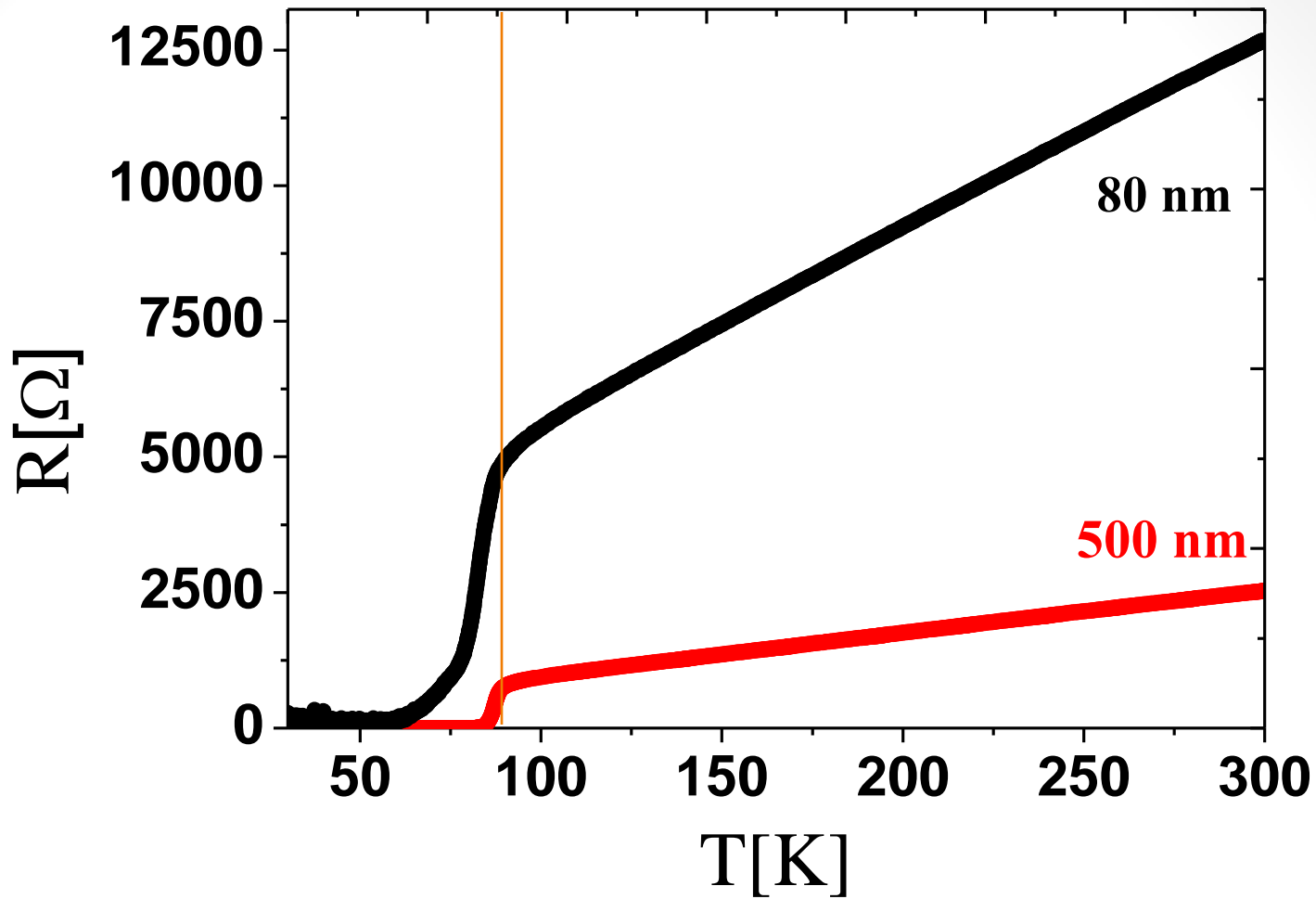
Laser ablated ~ 10 nm thick film
AFM image ($1\mu\text{m} \times 1\mu\text{m}$)



Bridges ($L = 400\text{-}700$ nm, $w = 80 - 500$ nm) were patterned

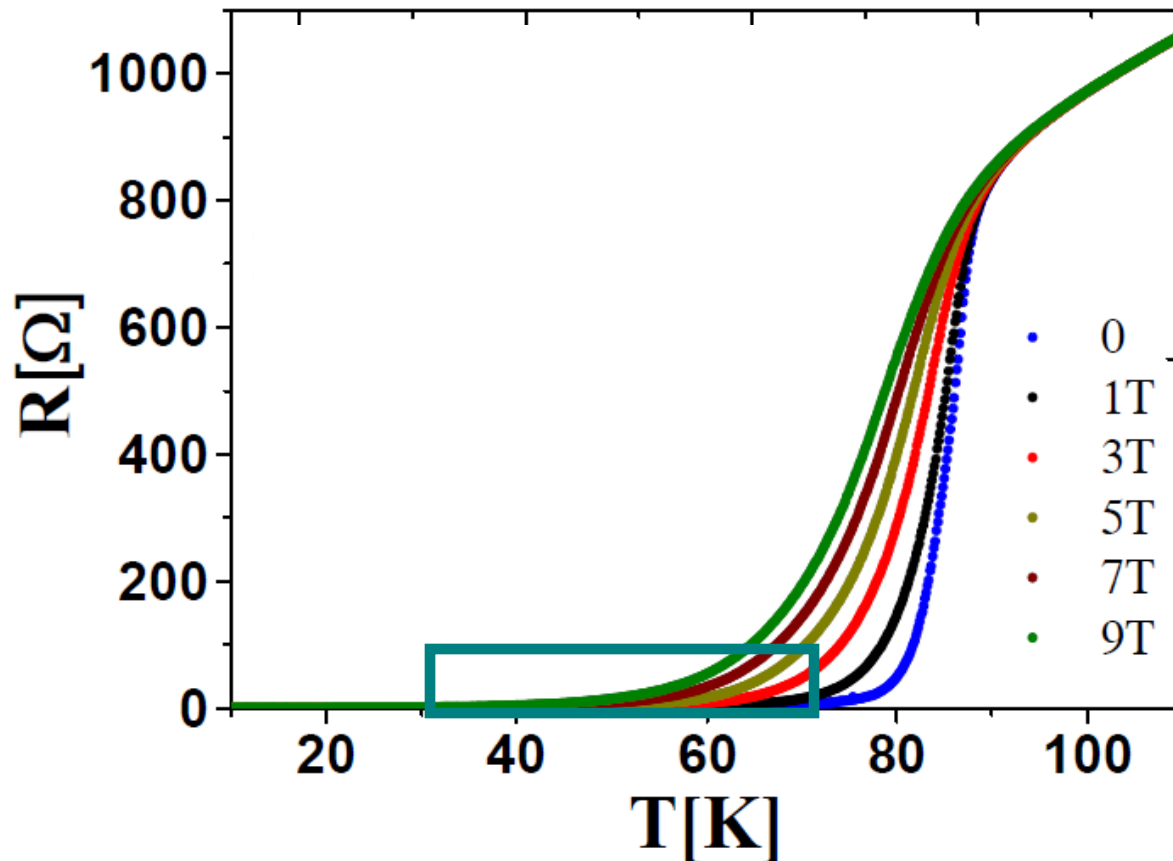
R vs. T --- YBCO wires





Similar $T_{\text{onset}} = T_c$ (~ 89 K) for all samples

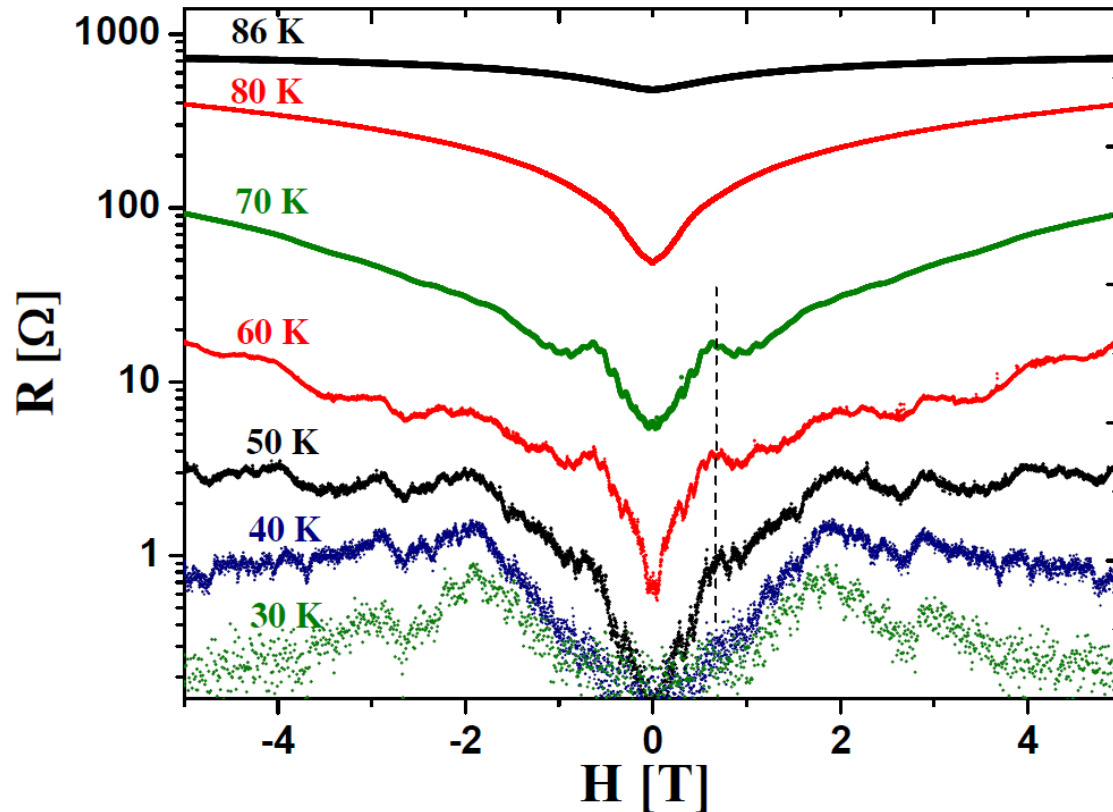
R vs. T (500 nm)



- Resistive transition broadening
- $R(T)$ curves cut at low temperature

R vs. H (500 nm)

MAGNETORESISTANCE BACKGROUND



a). Strong dependence on H at low fields / Weak dependence at high fields

b). T-independent characteristic field [‘matching’ field]

c). $dR/dT < 0$ at low T

Previous observations of $dR/dH < 0$

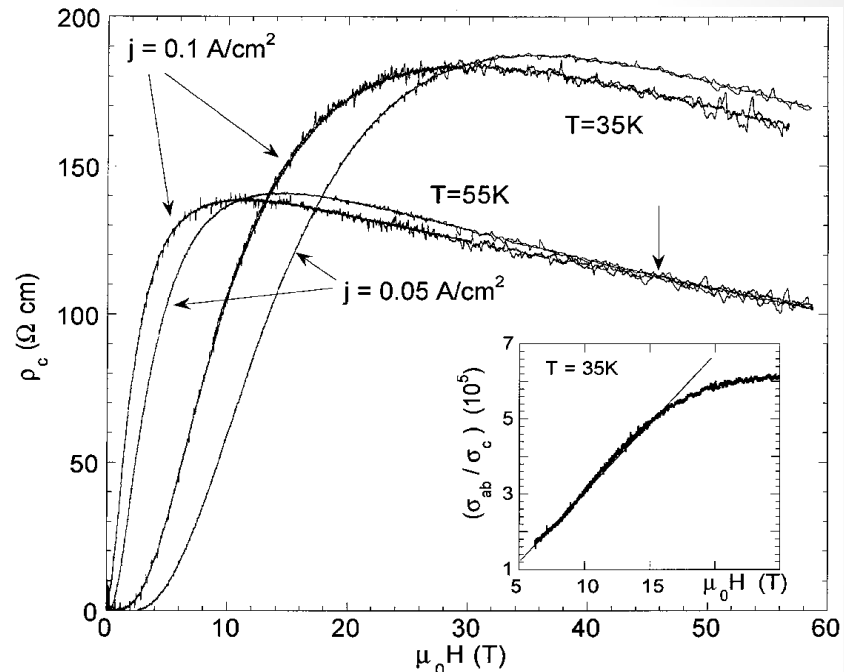
A. *c*-axis conductivity in high- T_c crystals

1/ $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+d}$

Morozov, Krusin-Elbaum,
Bulaevskii *et al.* PRL (2000).

2/ $(\text{LaSe})_{1.14}(\text{NbSe}_2)$

Szabó *et al.* PRL (2001).



c-axis conductivity in a d-wave SC is a parallel, two-channel tunneling process between neighboring layers:

(a) Tunneling of **Cooper pairs**

($\sigma \downarrow H$).

(b) Tunneling of **quasiparticles** in gapless regions

($\sigma \uparrow H + c$ due to increase in the QP DOS).

Previous observations of $dR/dH < 0$

B. *Low- T_c SC -- confined geometries*

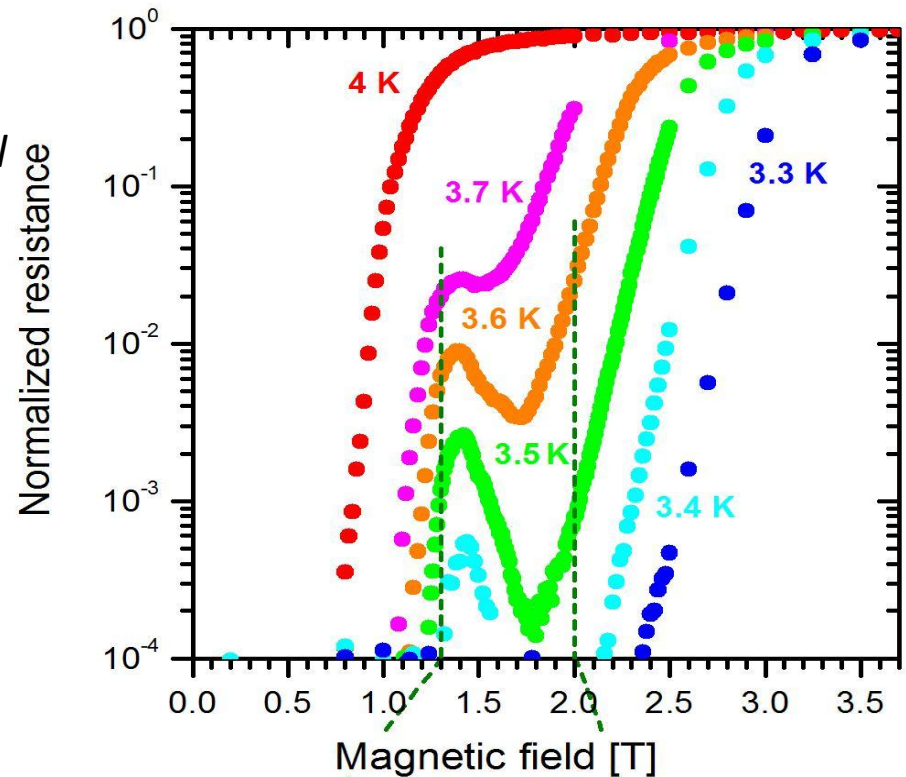
3/ Amorphous **Pb** ultrathin films

(Gardner, Xiong, *et al.*, Nature Physics (2011))

4/ Tungsten-based *nanowire* and **TiN** networks

(Córdoba, Baturina, Vinokur *et al.*
Nature Commun (2013))

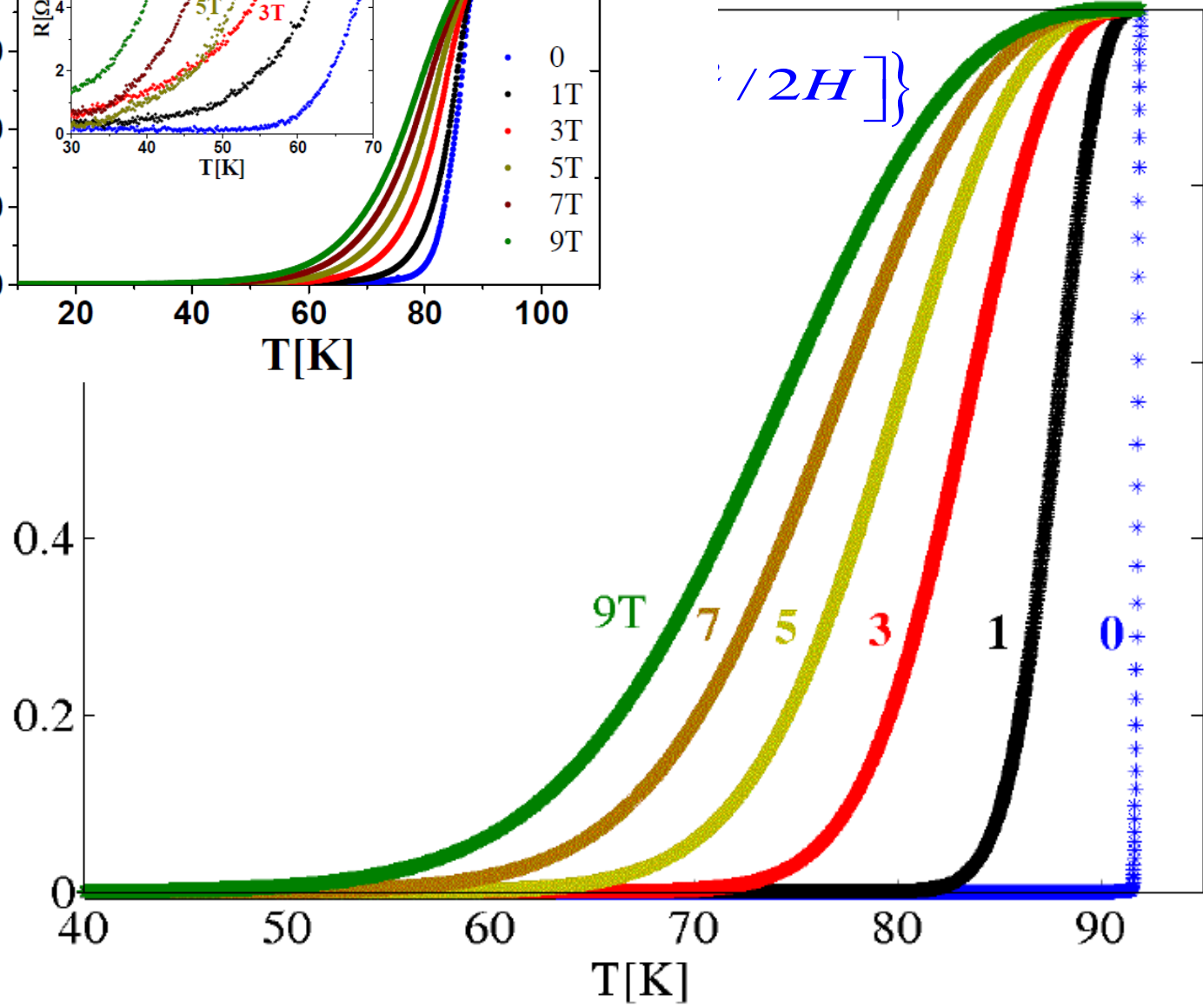
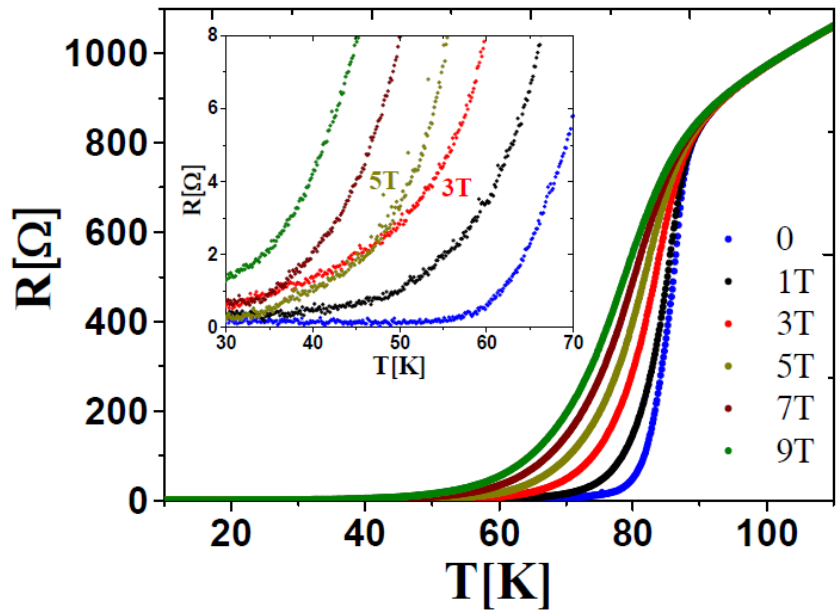
Surface SC is behind $dR/dT < 0$
(shunting the resistive part at
the middle of the sample).



Magnetoresistance background is attributed to three different mechanisms

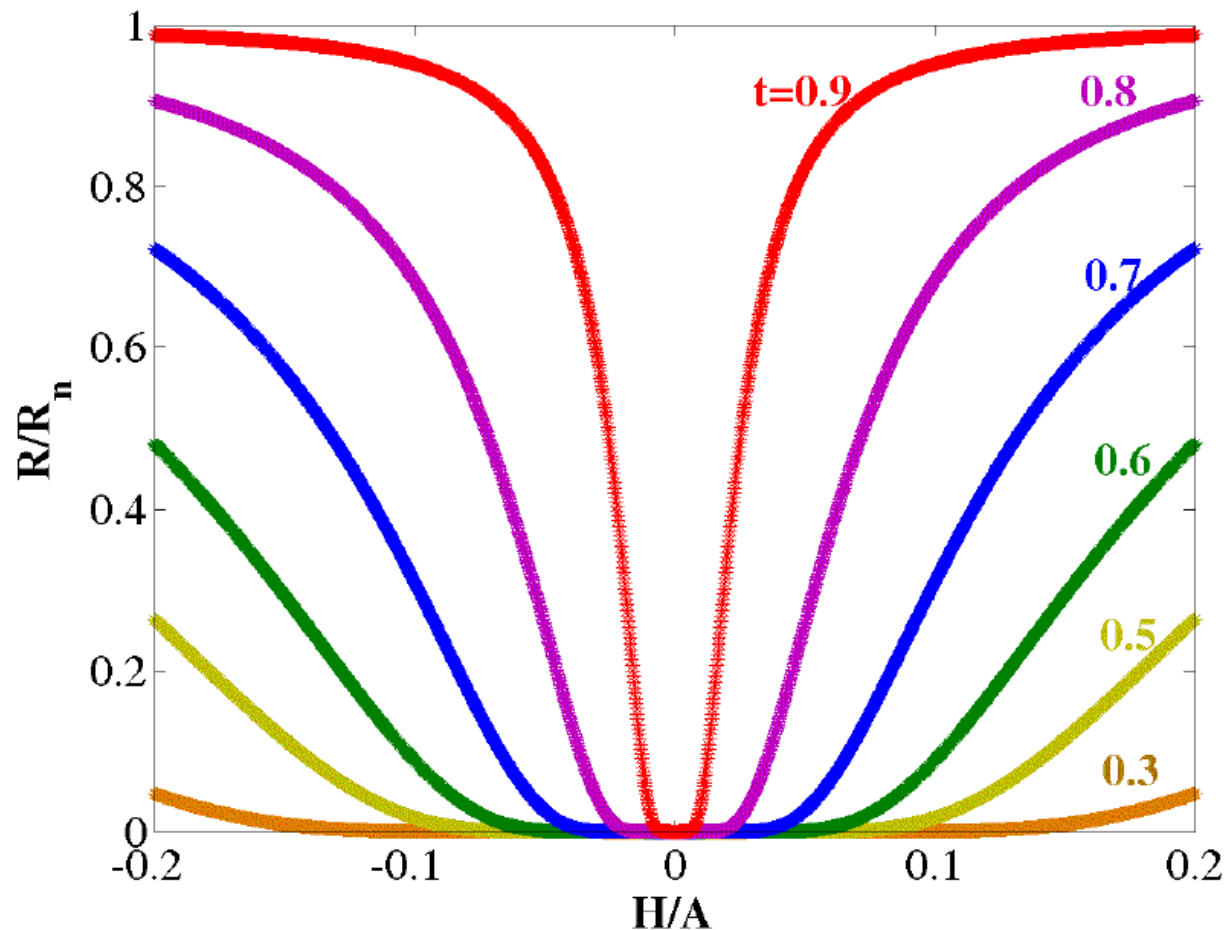
- **Low fields:** Thermally activated phase slips in weak links
(‘soft’ component – responsible for low H behavior)
- **High fields:** Thermally activated phase slips in grains
(‘hard’ component - responsible for high H behavior)

due to phase slips
Sukkar/Halperin, PRL (1969)

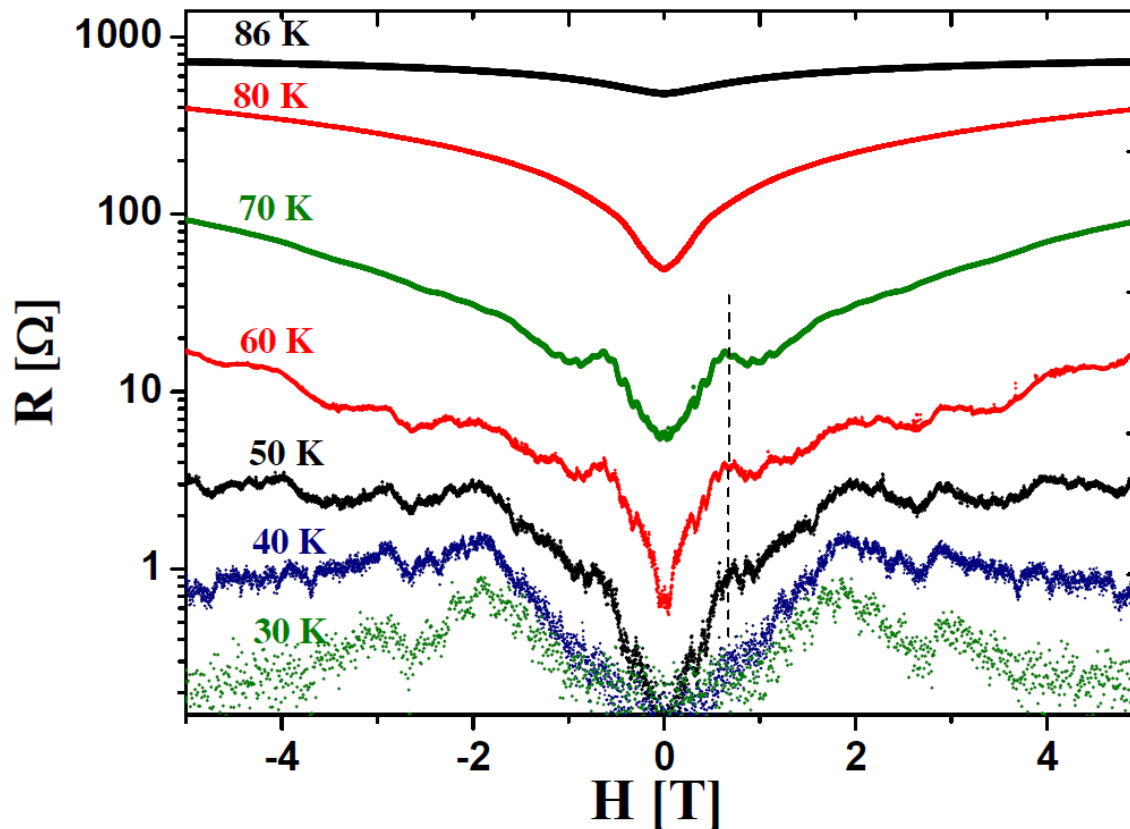


Magnetoresistance at different temperatures

(derived from Tinkham's model)



- Flat at “ R_n ”
- As T decreases onset is pushed to larger fields

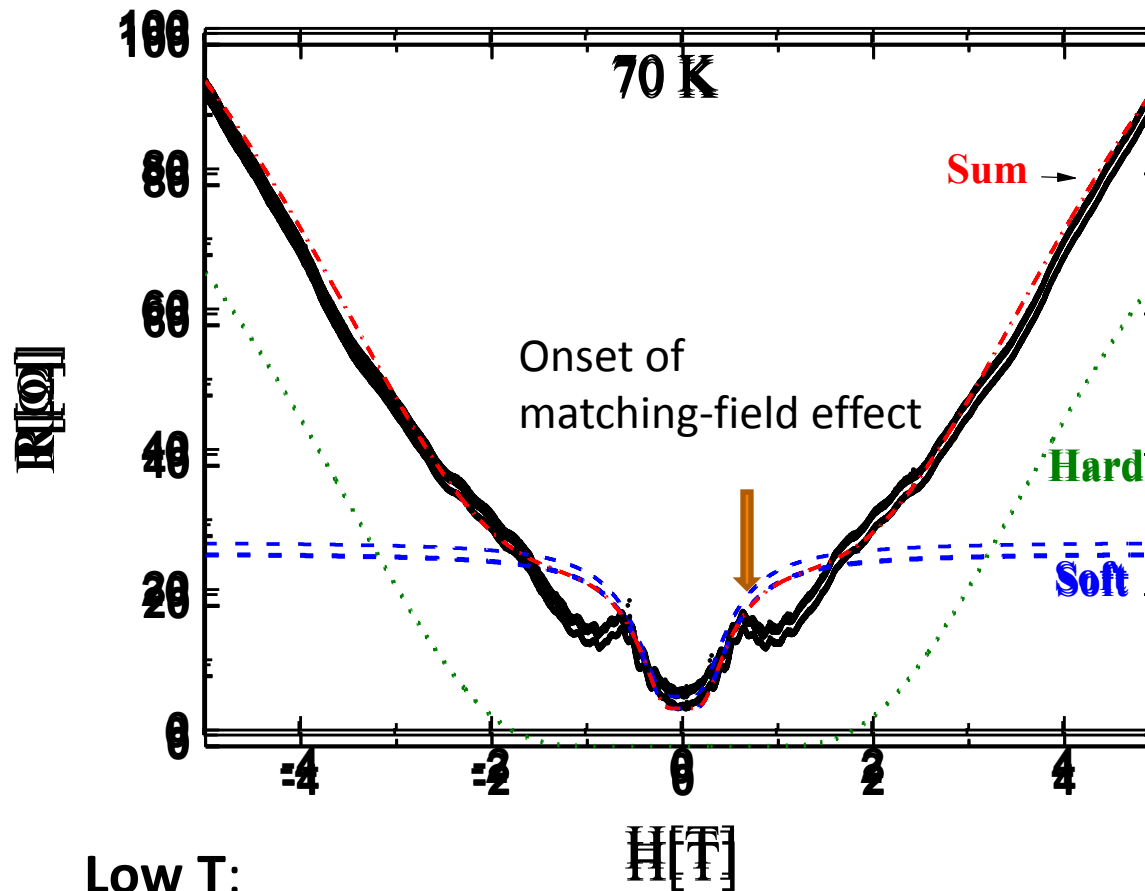


Fits to Tinkham's model have been unsuccessful

Data imply TWO contributions:

Weak links / grains ('soft' / 'hard' components)

Illustration of Tinkham's model for MR from soft and hard components

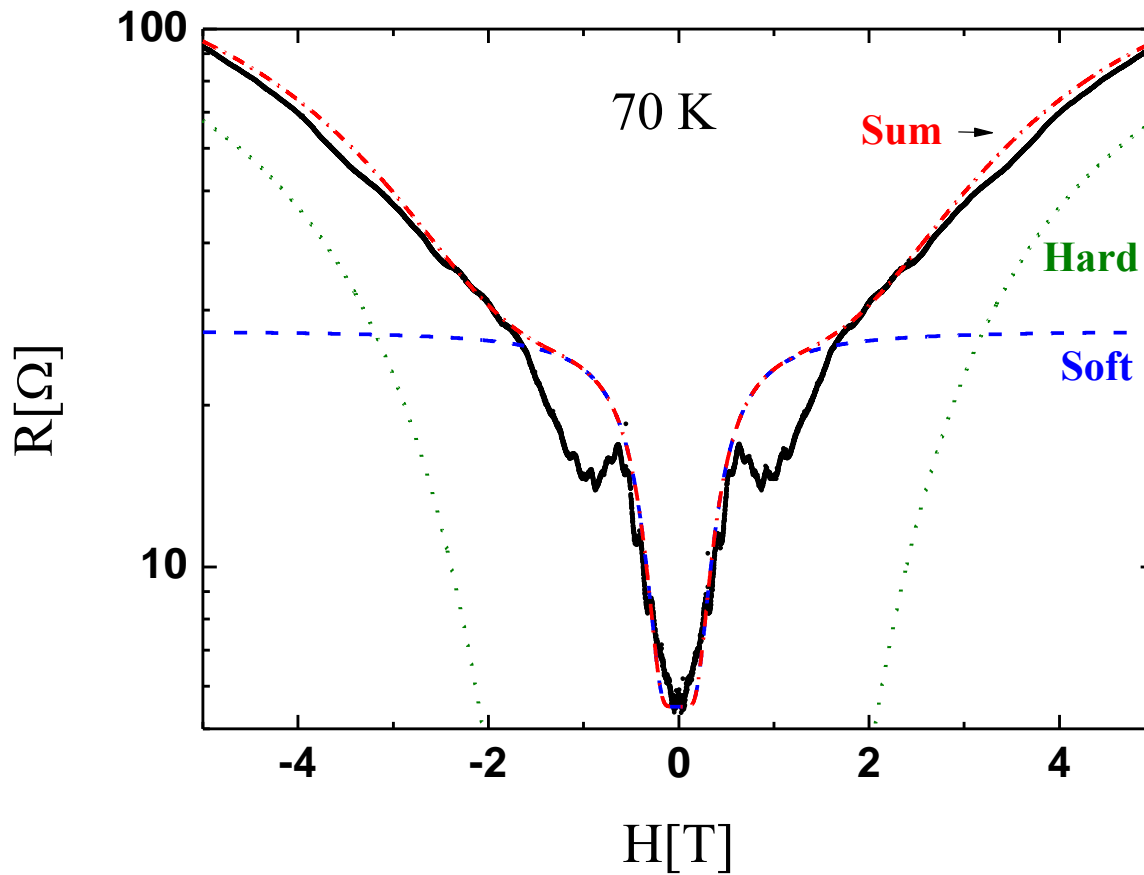


Low T:

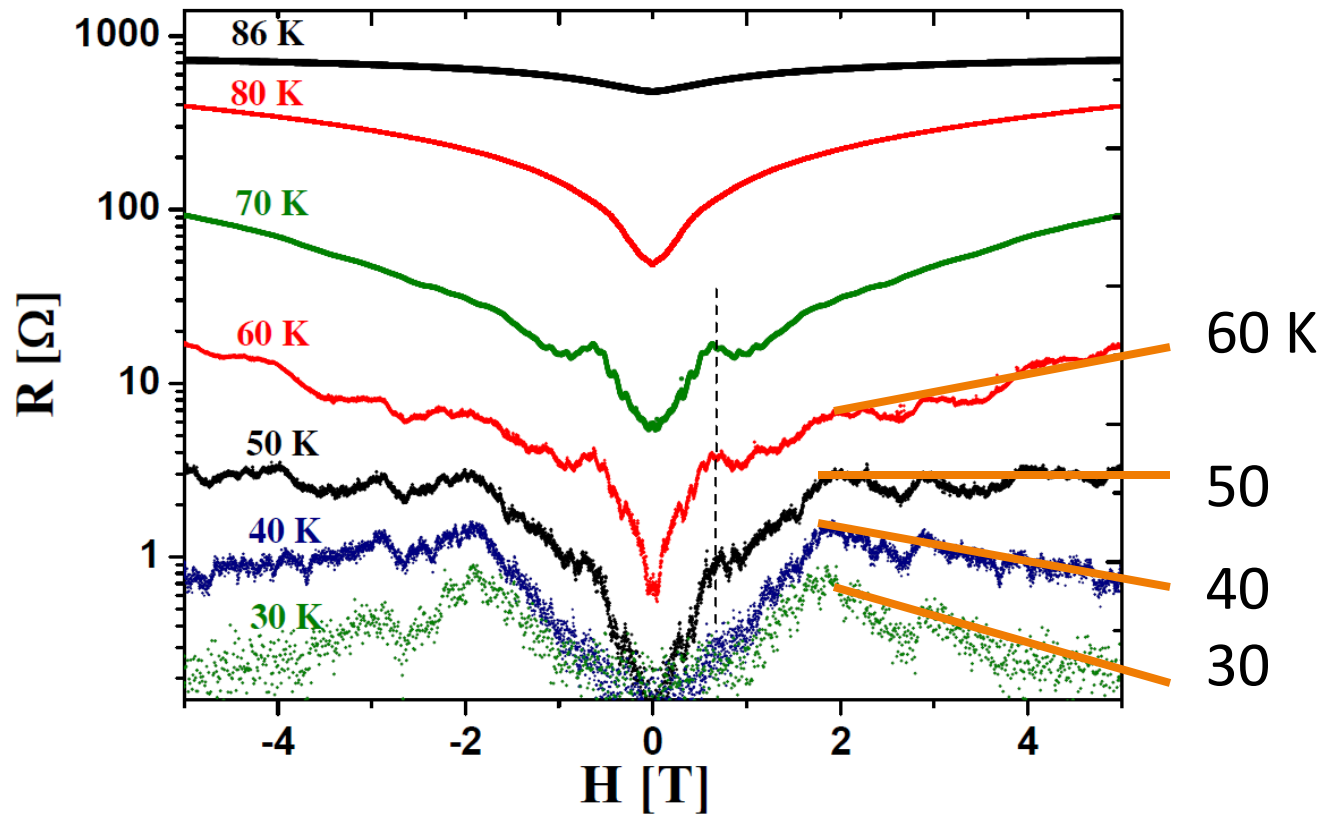
$$R_{\text{hard}} = 0$$

$$dR_{\text{soft}}/dH \sim 0$$

MR log scale



MAGNETORESISTANCE BACKGROUND: $dR/dT < 0$



$dR/dH < 0$ at low temperatures

ORIGIN: Quasiparticles tunneling.

(High H: vortices \rightarrow increased DOS $\rightarrow \sigma_{qp}$ H)

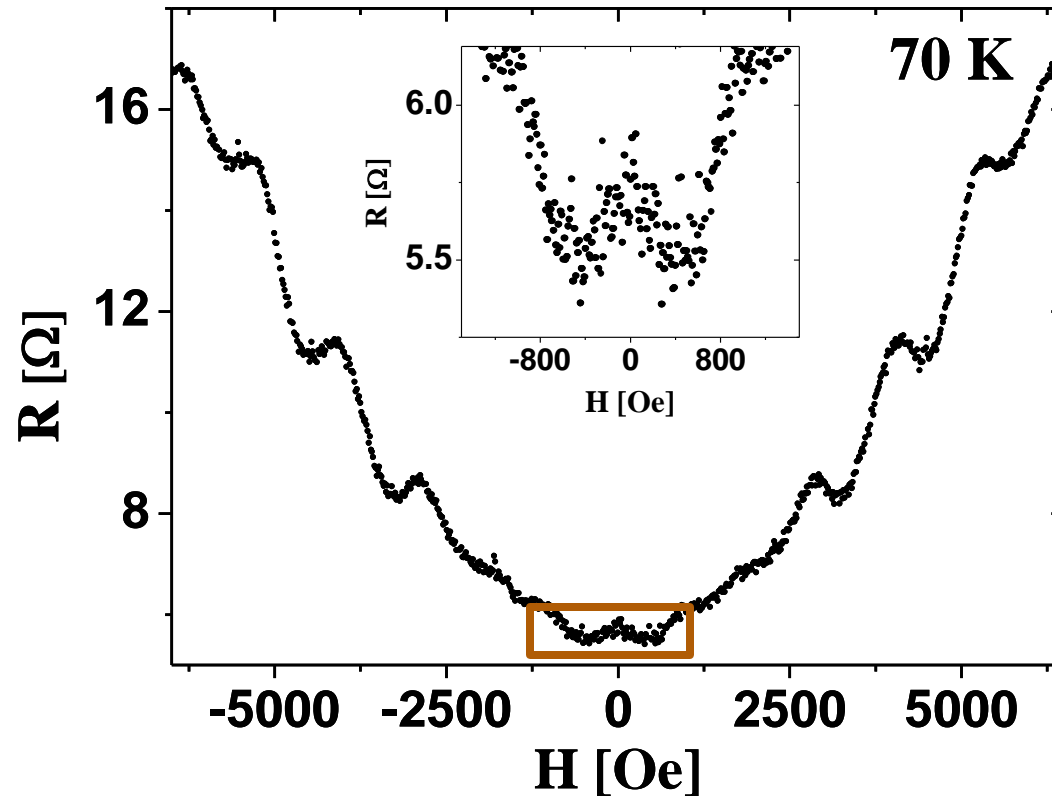
Mechanism revealed at low T where $R_{hard} = 0$ and dR_{soft}/dT small

Magnetoresistance background

- **Low fields:** Thermally activated phase slips in weak links
- **High fields:** Thermally activated phase slips in grains
- **Low temperatures - High fields :** Quasiparticles tunneling
(High H: vortices \rightarrow increased DOS $\rightarrow \sigma_{qp} \uparrow H$)

Mechanism revealed when $R_{\text{hard}} = 0$ and dR_{soft}/dT small

Oscillations and negative magnetoresistance (500 nm)



Oscillations

Negative magnetoresistance

Explanations proposed for the negative magnetoresistance in low- T_c SC

Pair scattering rate from magnetic impurities is reduced due to spin polarization in the presence of the field

(Simons *et al.* PRB (2012)).

[Origin of magnetic impurities???]

Disorder \rightarrow Random distribution of negative and positive Josephson critical currents

(Spivak and Kivelson, PRB (1991))

[Relevant near SIT)

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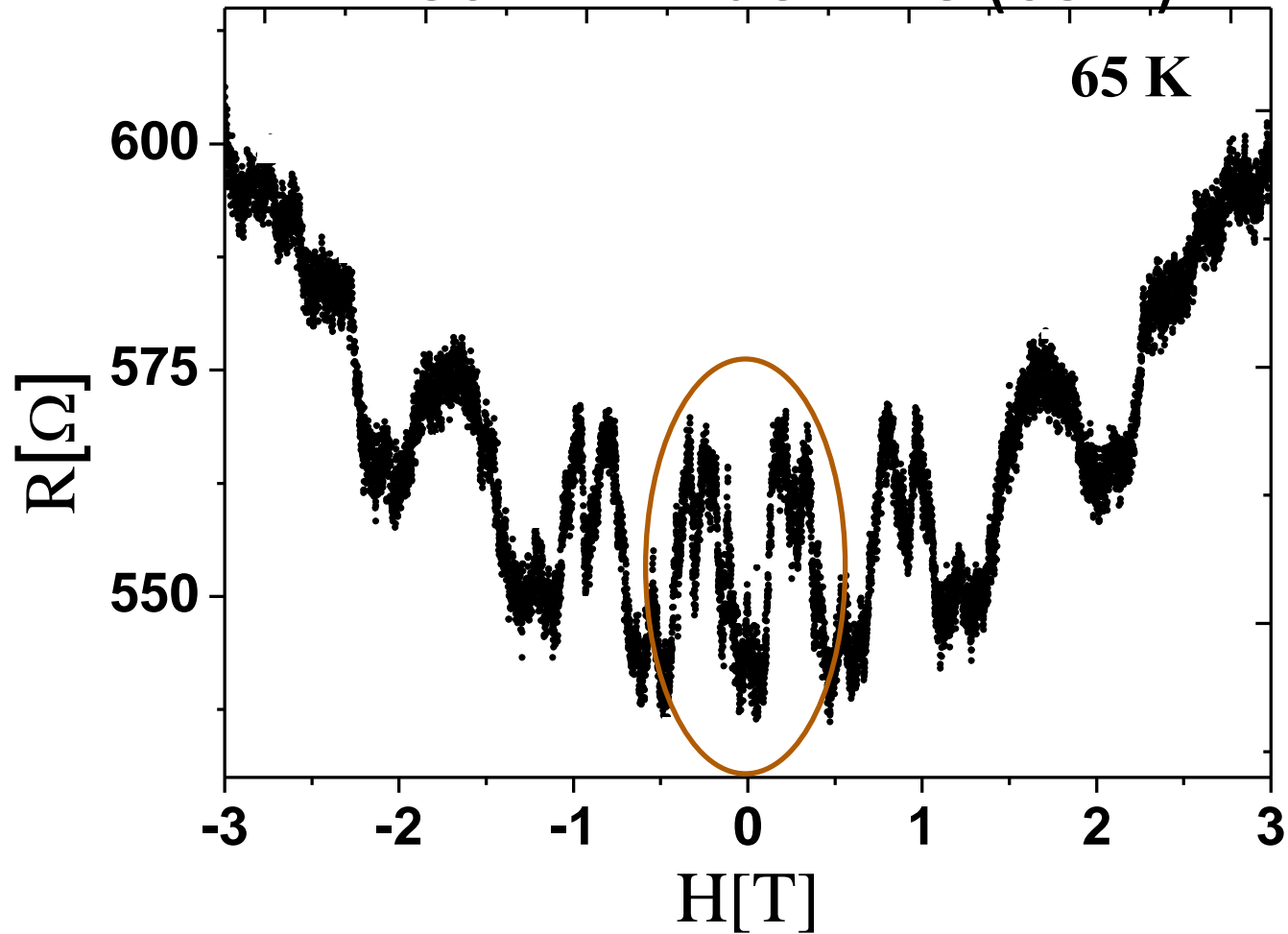
All models concern the initial slope ($dR/dH|_{H=0}$)

All models (proposed for the negative MR observed in low- T_c SC concern the initial slope ($dR/dH_{H=0}$))

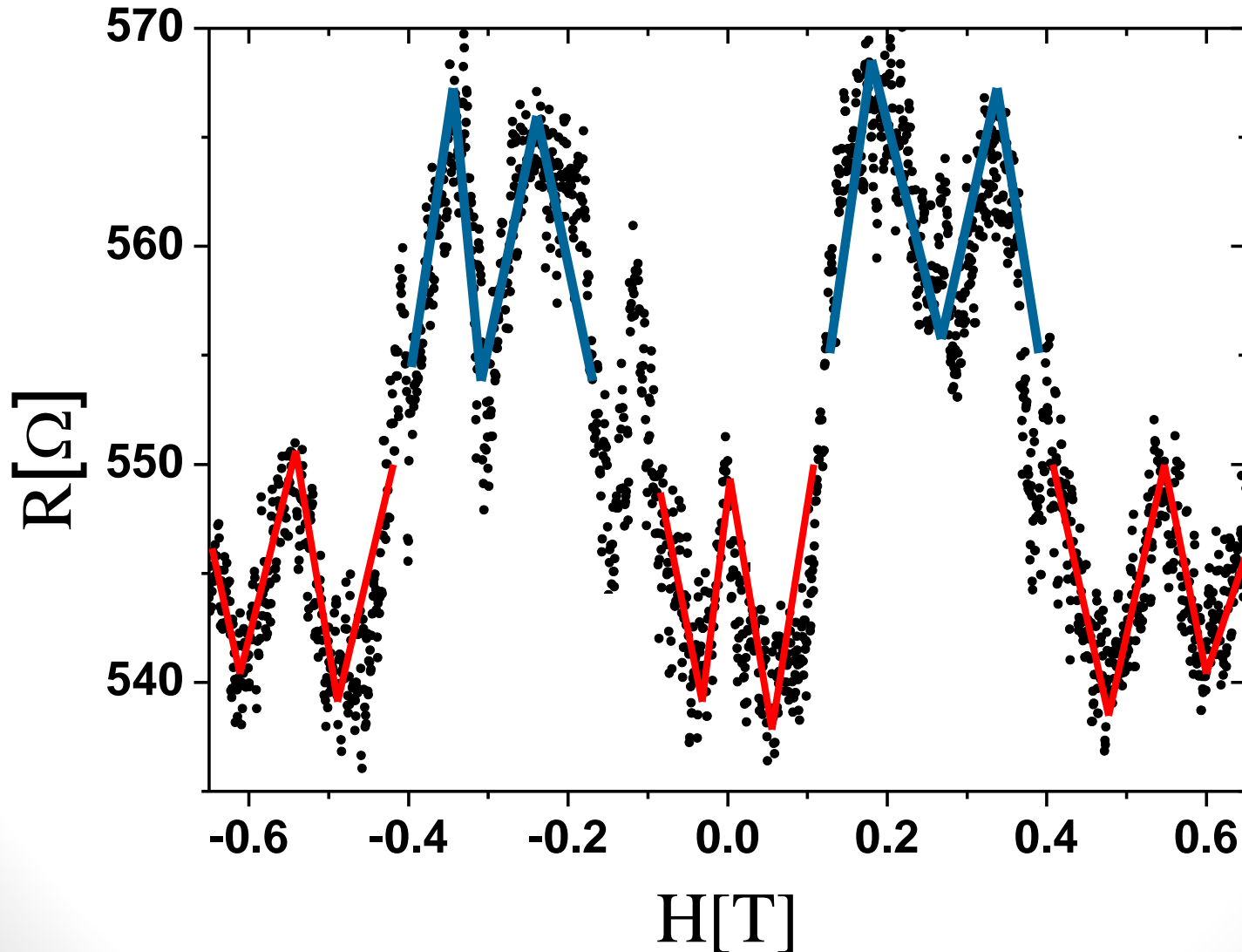
YBCO nano wires:

The **negative magnetoresistance** is part of the **periodic** behavior

80 nm wide wire (65 K)



YBCO nano wire: **PERIODIC** negative magnetoresistance
(Negative MR is part of the oscillatory behavior)



YBCO nano wires:

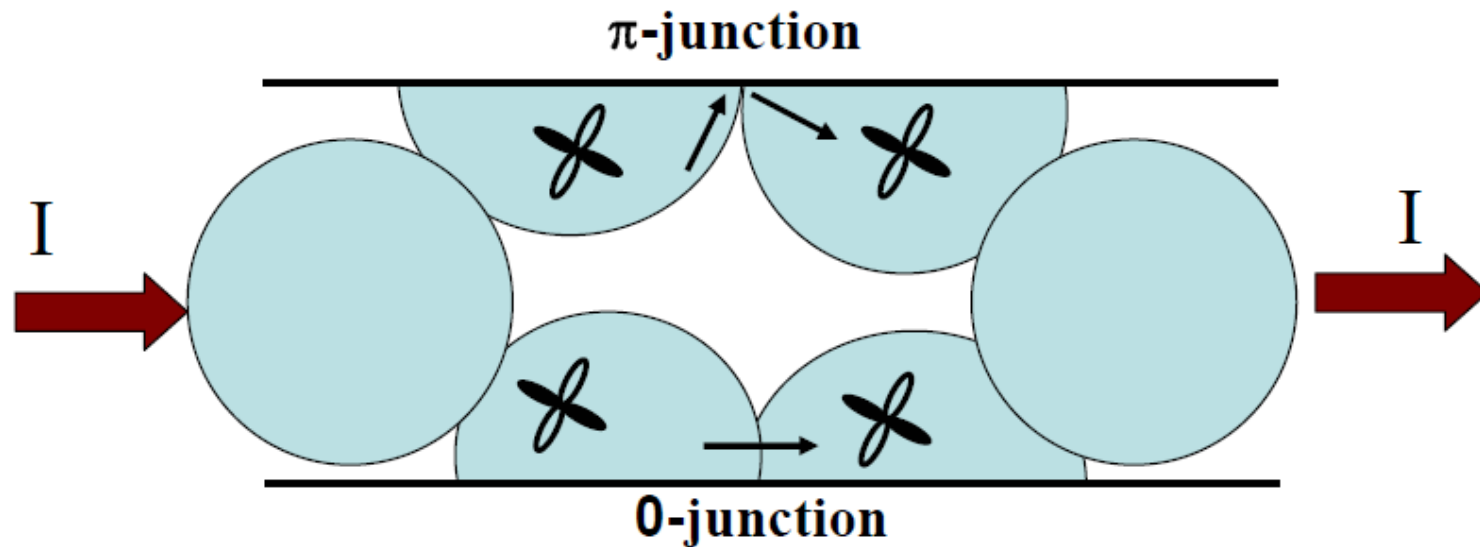
The **negative magnetoresistance** is part of the **periodic** behavior

Origin

π -junctions included in phase coherent loops
induce a π phase shift

Origin for both negative magnetoresistance and oscillations

Origin of negative MR : π -junctions



'Geometric' Josephson junctions

Reflected particles at the constriction suffer a sign change of the pairing potential, leading to a π shift.

After Gumann, Iniotakis and Schopohl, *APL* **91** (2007) 192502.

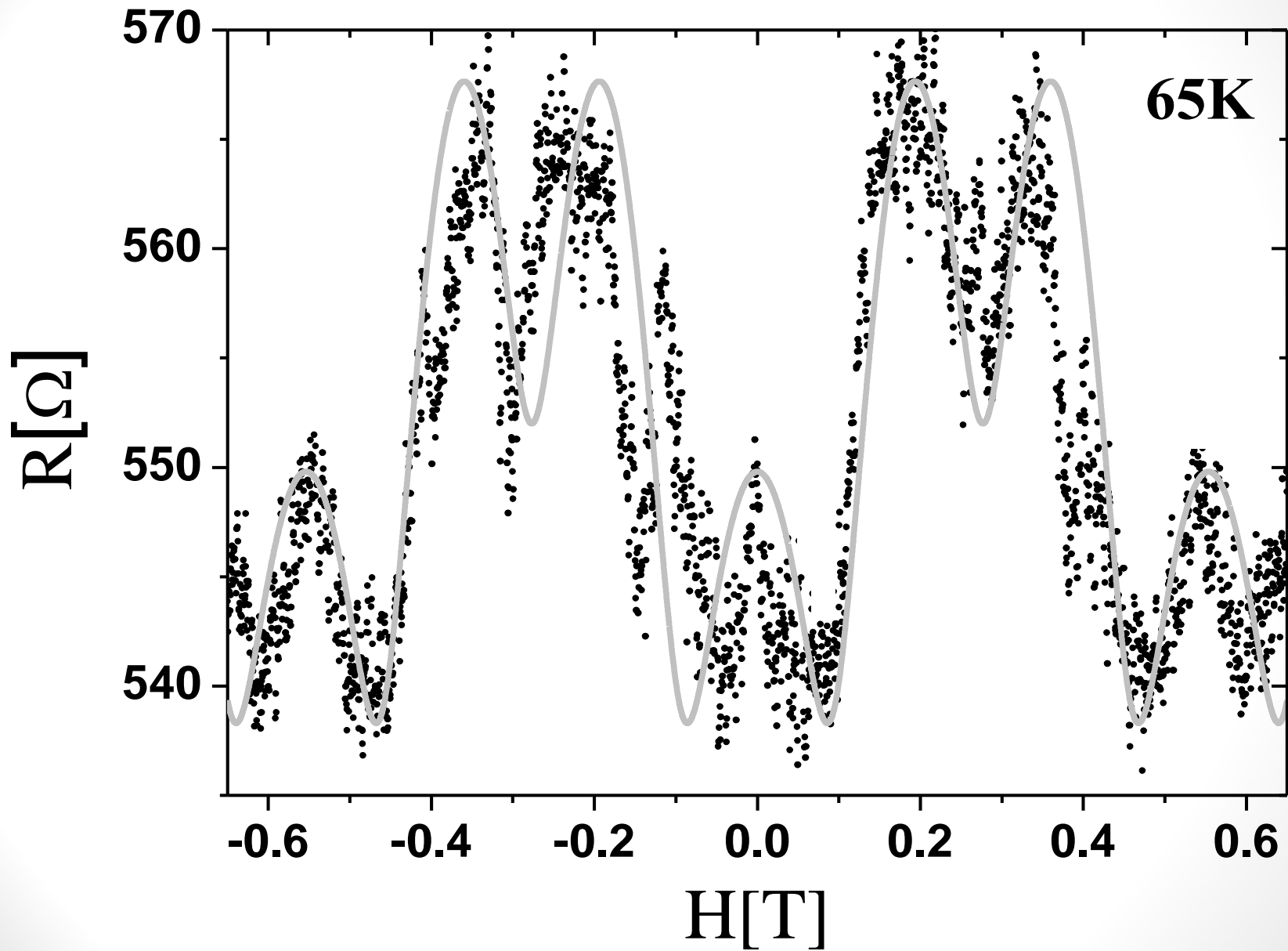
Model: Zero and π -SQUIDs in series

(Negative MR and oscillations have same origin)

- The presence of a SQUID is necessary in order to produce the periodic negative magnetoresistance.
- The two main field-periods (~ 2200 and ~ 6600 Oe) suggests that two SQUIDs with areas differing by a factor of ~ 3 play a role.
- The geometrical constraints of the wires (ratio of the wire width to the grain size of order 1) force these SQUIDs to be connected in series.

Voltage across 0-SQUID and π -SQUID connected in series

$$V = (R_1 / 2) \sqrt{I^2 - \left(2I_{c1} \cos \frac{\pi SH}{\Phi_0} \right)^2} + (R_2 / 2) \sqrt{I^2 - \left(2I_{c2} \sin \frac{\pi(3S)H}{\Phi_0} \right)^2}$$



Summary

Phenomenon

Origin

1. Background

High T low fields MR

Phase slips - weak links

High T high fields MR

Phase slips - grains

Low T – negative slope dR/dT

QP tunneling

2. Oscillations

Low fields – phase coherent loops

High fields – matching

3. Negative MR

Phase coherent loops

Loops include π - junctions